## IAP20 Ros 1707. TO 02 FEB 2005heet 1 of 1

## ATTY. DOCKET NO. Notice assigned 22 INFORMATION DISCLOSURE TCP-004 APPLICANT CITATION IN AN Kenii WATANABE et al APPLICATION FILING DATE GROUP herewith (PTO-1449) U.S. PATENT DOCUMENTS FILING EXAMINER'S PATENT NO. DATE NAME CLASS SUBCLASS INITIALS DATE FOREIGN PATENT DOCUMENTS EXAMINER'S COLINTRY CLASS SUBCLASS DATE PATENT NO INITIALS /G.N.R./ IP abstract 2001-72499 03/21/2001 /G.N.R./ 6-219899 08/09/1994 JP abstract OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.) GNR/ TANIGUCHI et al: "Spontaneous nucleation of cubic boron nitride single crytal by temperature gradient method under high pressure;" Journal of Crystal Growth, 2001, vol. 222, pages 549-557. FUKUNAGA et al; "Nucleation and growth of cubic boron nitride using a Ca-B-N solvent"; Diamond /G.N.R./ and Related Materials, 2004, vol. 13, pages 1709-1713. AKAMARU et al; "Pressure dependence of the optical-absorption edge of A1N and graphite-type /G.N.R./ BN": Journal of Physics and Chemistry of Solids; 2002, vol. 63; pages 887-894. WATANABE et al; "Direct-bandgap properties and evidence for ultraviolent lasing of hexagonal /G.N.R./ boron nitride single crytal"; Nature Materials, 2004, vol. 3, No. 6, pages 404-409. EXAMINER /G. Nagesh Rao/ (12/25/2008) DATE CONSIDERED 12/25/2008

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609, draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.